

isc N-Channel MOSFET Transistor

2N60

• FEATURES

- Drain Current I_D= 2A@ T_C=25 °C
- Drain Source Voltage-
 - : V_{DSS}= 600V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 5.0 \Omega (Max)$
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

PIN 1.Gate 2.Drain 3.Source TO-251 package

APPLICATIONS

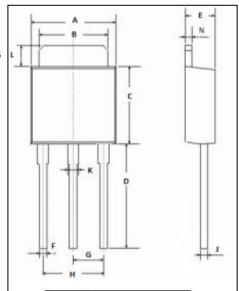
Switching power supplies, converters, AC and DC motor controls

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	600	V	
V _{GS}	Gate-Source Voltage-Continuous	±30	V	
ΙD	Drain Current-Continuous	2	Α	
I _{DM}	Drain Current-Single Plused	8	А	
P _D	Total Dissipation @T _C =25°C	44	W	
Tj	Max. Operating Junction Temperature	150	$^{\circ}$	
T _{stg}	Storage Temperature	-55~150	$^{\circ}$	

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R _{th j-c}	Thermal Resistance, Junction to Case	2.8	°C/W



DIM	mm		
DIM	MIN	MAX	
A	6.35	6.45	
В	5.20	5.40	
C	5.30	5.50	
D	8.00	8.20	
E	2.30	2.50	
F	0.50	0.60	
G	2.10	2.40	
Н	4.15	4.15 4.45	
J	0.40 0.60		
K	0.70	0.90	
L	1.40	1.60	
N	0.55	0.65	



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• ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYPE	MAX	UNIT
V _{(BR)DSS}	Drain-Source Breakdown Voltage	V _{GS} = 0; I _D =250μA	600			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} = V _{GS} ; I _D =250μA	2.0		4.0	٧
V _{SD}	Diode Forward On-voltage	I _S = 2A ;V _{GS} = 0			1.4	٧
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D = 1A			5.0	Ω
Igss	Gate-Body Leakage Current	V _{GS} = ±30V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =600V; V _{GS} = 0			10	μΑ

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